P roduction of G as P hase Z inc O xide N anoclusters by P ulsed Laser A blation

I. O zerov,¹, A.V. Bulgakov,² D.K. Nelson,³ R.Castell,⁴ and W. Marine^{1, y}

¹CRMC-N, UPR 7251 CNRS, Universite de la Mediterranee, Case 901, 13288 Marseille Cedex 9, France.

² Institute of Therm ophysics SB RAS, 1 Lavrentyev Ave., 630090 Novosibirsk, Russia.

³A F. Io e Physico-Technical Institute, Polytechnicheskaya 26, 194021 St.-Petersburg, Russia.

⁴Universidad Sim on Bol var, 1080 Caracas, Venezuela.

(D ated: A pril 14, 2024)

W e present experim ental results on the photolum inescence (PL) of gas-suspended zinc oxide nanoclusters prepared during ablation of sintered ZnO targets by a pulsed A rF laser in the presence of oxygen am bient gas. The PL spectra in the UV spectral region correspond to the exciton recom bination in the nanoclusters which are crystallized and cooled down to the tem perature of the am bient gas in the ablation cham ber. The tim e evolution of the spectra as well as their dependence on the am bient gas pressure are discussed.

PACS numbers: 81.15Fg, 81.05Ys, 78.55Et, 61.80Ba. Keywords: Zinc oxide; Nanoclusters; Photolum inescence; Laser ablation.

I. IN TRODUCTION

Nanocrystalline wide-gap sem iconductors have attracted a great interest due to their in portance in fundam ental research and potential technological applications. In particular, zinc oxide is considered as one of the most prom ising materials for realization of optoelectronic devices like UV light em itting diodes and lasers [1, 2, 3, 4]. Several physical and chem ical methods like molecularbeam epitaxy [1], chem ical vapor deposition [5], sputtering [6] have been successfully applied for ZnO lm synthesis. The technique of nanosecond [2, 3, 4, 7, 8, 9] and fem to second [10] pulsed laser ablation (PLA) has been also widely used to produce both epitaxial and nanostructured ZnO Im sofhigh optical quality. The synthesis of nanocrystalline Im s is usually perform ed in an am bient gas whose pressure should be high enough, rstly, to con ne the plasm a created after laser ablation in order to favor the collisions and chem ical reactions in the laser induced plum e and, secondly, to induce a rapid cooling of the plasm a to favor the condensation of the nanoclusters in gas phase [11]. Previous experimental optical studies of the laser-induced plum es [12, 13] in vacuum and in am bient gas did not show the evidence for ZnO cluster formation. Recently, we have observed small nanoclusters with composition Zn_nO_m (with n; m up to 15) by timeof- ight mass-spectrom etry [14] in vacuum and in gas at low pressures. The form ation of these atom ic clusters in laser induced plasm a can be considered as the step in the synthesis of clusters with sizes of several nanom eters which are usually deposited on a substrate individually or in form of a thin lm [8, 9, 11]. Despite of num erous reports on laser deposition of nanostructured lm s, few data are available on the origin of the nanoclusters and on their aggregate state during the transport to the

substrate. However, this inform ation is crucial to control and, consequently, optim ize the deposition conditions of nanostructured lm s. In this paper we show that ZnO nanoclusters are well form ed in the gas phase and we present the results on in situ photolum inescence from the clusters during their synthesis by PLA in the oxygen am bient.

II. EXPERIMENTAL

The nanoclusters were prepared by pulsed laser ablation of a sintered ZnO target. The target was placed inside a stainless steel chamber on a rotating holder. A fter evacuating the chamber down to a pressure of about 2 10⁷ m bar by a turbom olecular pump, a continuous slow ux of oxygen, used as am bient gas, was introduced into the cham ber at a controlled pressure ranging from 2 to 8 m bar. An ArF excimer laser (Lambda Physik LPX 205) operating at a wavelength of 193 nm with pulse duration of 15 ns (FW HM) was used for the ablation. The laser beam was focused onto the target with an incident angle of 45 and the uence was about 3.5 J/cm^2 . The choice of these conditions was guided by our previous results on the deposition of nanocrystalline Im s [8]. A typical ablation run time was about 5 m inutes, that corresponds to 900 laser shots at a repetition rate of 3 Hz. A fter the end of the ablation procedure, the photolum inescence (PL) spectra of the clusters have been taken in situ. The photolum inescence was excited either by the non-focused beam of the ArF laser or by the 3rd harm onic of a Tisapphire fem to second laser (Spectra Physics, = 266 nm, = 100 fs) and analyzed by a double m onochromator (Jobin-Yvon, DH-10) provided with a photom ultiplier and a boxcar integrator (Stanford SR-250). The system was synchronized using an external delay generator (Stanford DG-535). The boxcar was started before the laser shot and the gate was 50 ns in order to overcom e the tim ing jitter problem . G ated intensi ed CCD cam era (Andor DH-734) was used for rapid im aging.

E lectronic address: ozerov@ crm cn.univ-m rs.fr

^yE lectronic address: m arine@ crm cn.univ-m rs.fr

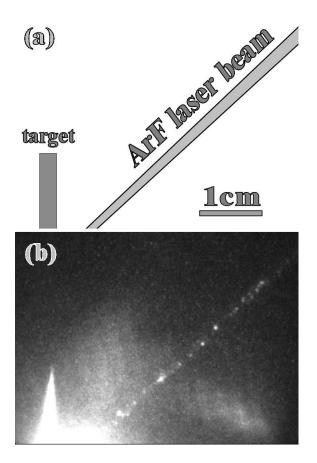


FIG.1: (a) Sketch of the ablation geometry. (b) I-CCD camera in age of ZnO nanoclusters excited by incident ArF laser beam .

III. RESULTS AND DISCUSSIONS

D uring the experim ents on the deposition of nanocrystalline Im s we have observed the presence of ZnO aggregates suspended in the gas by an intense lum inescence along the path of the incident ablating ArF laser beam as illustrated in Fig. 1. Figure 1a shows a sketch of the ablation system. The target is situated at the left lower part of the image and the ablating laser beam hits the target at a 45 incident angle. Figure 1b presents an iCCD camera im age which was taken simultaneously with the ablation laser pulse. One can clearly see the lum inescent particles in the path of the ablating laser beam. The clusters have been accumulated in the gas phase from precedent laser shots and slowly displaced within the ambient gas. The lum inescence is observed after several ablation shots needed for accumulation of a detectable quantity of the clusters in the chamber. The clusters are the product of a complex process including gas phase condensation and laser-induced fragm entation. At the observation point situated far from the focal plane, the uence of the focused ArF laser beam was about 200 $m J/m^2$. This uence is fairly high to induce the evaporation of atom ic species from the nano-aggregates and

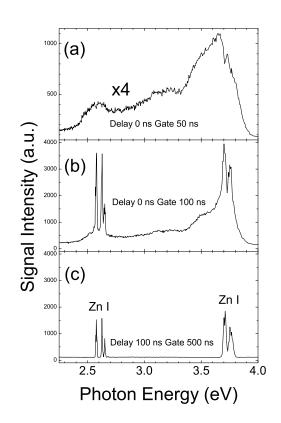
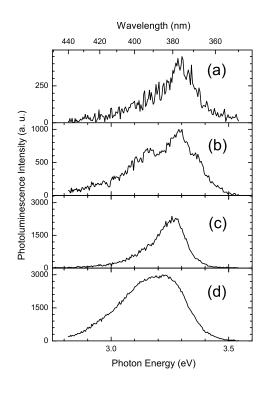


FIG.2: Fragmentation of gas-suspended ZnO nanoclusters excited by ArF laser (uence 200 mJ/cm^2): (a) Boxcar delay 0 ns, gate 50 ns; (b) delay 0 ns, gate 100 ns; (c) delay 100 ns, gate 500 ns. The oxygen pressure was 4 m bar. The atom ic lines of Zn are indicated in the gure. The observation point was at a distance of 5 cm from the target.

their fragm entation [15, 16]. The corresponding lum in nescence spectra are shown in Fig. 2. The spectrum in Fig. 2a was taken during the laser pulse. The spectrum presents several superposed bands originated from both emission of ZnO nanoparticles and the continuum due to the brem sstrahlung emission [13]. At a time delay of about 50 ns relatively to the laser pulse, narrow emission lines of atom ic zinc appeared in the spectrum together with the continuum emission (Fig. 2b). These Zn atom s are desorbed or evaporated from clusters. At longer delays the spectrum consists of only zinc atom ic lines (Fig. 2c).

In order to prevent the fragm entation of the nanoclusters during the PL m easurem ents, we have accum ulated the clusters in gas phase and studied their PL under the excitation by additional laser beam s after the end of the ablation nun. Figure 3 shows the PL spectra of the gassuspended ZnO nano-aggregates prepared in the oxygen am bient gas at di erent pressures. The spectra have been taken just after the ablation nun and have been excited by a non-focused A rF laser beam. The PL intensity increases with am bient gas pressure indicating the increase



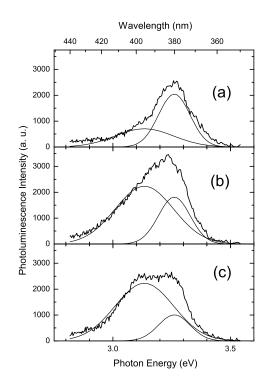


FIG.3: PL spectra of gas-suspended ZnO nanoclusters excited by ArF laser (uence 25 35 m J/cm^2) taken just after the ablation run for di erent ambient gas pressures: (a) 2 m bar; (b) 6 m bar. PL spectra of a ZnO nanocrystalline lm excited at di erent laser uences: (c) 30 m J/cm^2 and (d) 90 m J/cm^2 .

FIG.4: Evolution of the PL spectra of gas-suspended ZnO nanoclusters. The oxygen pressure was 8 mbar. (a) 1st pass (0 m inutes); (b) 2nd pass (delay 3 m in); (c) 3rd pass (delay 6 m in). The uence of ArF laser was 30 m J/cm². Thin lines show the results of tting by two G aussians.

in the amount of clusters ying in the chamber. The spectra consist of a complex band of an asym metric shape maxim ized at a photon energy of 3.30 eV. The band have large tails expanding on both high and low energy sides of the spectrum.

W e attribute this photolum inescence to the ZnO nanoaggregates already crystallized and cooled by collisions with molecules of the ambient gas. The spectral position of the peak corresponds to the recombination of excitons in the clusters [8, 17]. We note that the defectrelated band observed usually in ZnO at photon energies of 2 2:5 eV [8] is absent. It is interesting to compare the PL of gas-suspended clusters with the PL obtained from a nanocrystalline In under similar excitation of 30 m J/cm² (Fig. 3c). The excitonic transition in the Im is observed at the photon energy of 3.28 eV and the spectrum is narrower than that observed for gas-suspended nanoclusters. A lso, the high energy tail is strongly reduced. The sizes of nanoclusters deposited in form of the

In were about 8 10 nm [8]. The maximum position of the exciton emission band from gas-suspended nanoclusters is shifted to about 20 meV higher photon energies compared to the PL from the lms. Both features, the blue shift of the peak and the high energy tail of the PL spectra indicate the possibility of the quantum con nem ent in sm all nanoclusters which are present in the gas phase. It m eans that a large am ount of gas-suspended clusters have the sizes com parable with the exciton B ohr radius which is 1.8 nm in ZnO [17].

All the spectra obtained from the nanoclusters under the nanosecond laser excitation have a low -energy tail of the exciton emission band comparable to that observed from a lm under high excitation (gure 3d). This low energy tail of the PL spectra of gas-suspended clusters exhibits a slow evolution in m inute time scale indicating the cluster coalescence dynam ics. Figure 4 shows the evolution of the PL spectra of ZnO nanoclusters prepared in 8 m bar of oxygen. The rst spectrum (Fig. 4a) was taken just after the ablation run. We should note the higher integral intensity of the spectrum com pared to those obtained at lower am bient gas pressure (Fig. 3a,b). This fact as well as stronger scattering of a continuous laser beam which we used to test for the presence of clusters indicate that the concentration of the nanoclusters increases with am bient gas pressure. At the same time, the shape of the PL peak observed in Fig. 4a is sim ilar to that observed for low er gas pressures. The second (Fig. 4b) and the third (Fig. 4c) spectra were taken 3 and 6 m inutes after the stone, respectively. The shape of the PL spectra indicates that they are originated from two di erent transitions. In order to separate the contri-

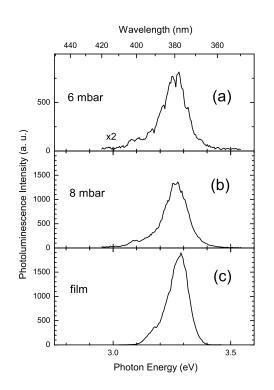


FIG.5: PL spectra of gas-suspended ZnO nanoclusters for dierent ambient gas pressures: (a) 6 m bar; (b) 8 m bar. PL spectrum of a ZnO nanocrystalline lm (c). The PL was excited by 3rd harmonics of the fem to second laser = 266 nm. The uence was about 300 J/cm²

butions of these two overlapped bands, the spectra have been deconvoluted by two G aussian functions. The maxim a of the bands are centered at 3.26 and 3.13 eV with FW HM of 0.13 and 0.25 eV respectively. The rst band decreases in intensity with time while the second, low energetic one, increases from the second spectra and then remains constant. The cluster PL signal taken at long time delays (Fig. 4b,c) is sim ilar in shape to that observed from a Im excited with high uence (Fig. 3d). These results provide evidence for the grow th and/or coalescence of the nanoclusters. It is known that the e ciency of light absorption by nanoparticles increases with the particle size (see [15] and references therein). Thus, when the clusters grow up they absorb m ore photons and m ore electron-hole pairs are created leading to the increase in the PL intensity.

Two possible mechanisms lead to the increase of the low energy part of the PL spectra. First, if high intensity laser excitation creates the electron-hole plasm a, the emission peak is shifted because of the bandgap energy (E_g) renorm alization. The red shift of the emission peak from ZnO epitaxial lm s with increase of the excitation intensity has been reported under fem to second excitation [19]. Second, the excitation laser beam can heat the nanoclusters resulting in the decrease of the optical bandgap and in the red shift of the interband transitions. By extrapolating the tem perature dependence of bulk ZnO optical bandgap [18], we found that the gap energy decrease down to 3.13 eV corresponds to heating up to a tem perature of about 550 $\,$ 600 K .

W hen photons with energy of 6.4 eV are absorbed in a m aterial with $E_q = 33$ eV hot carriers are created. The them alization of these hot carriers via electron-phonon interaction leads to the cluster heating on a time scale of several picoseconds followed by radiative recombination. In the case of non-radiative recom bination of the free carriers, all the photon energy is directly converted to heat. W e estim ate the increase in tem perature of a ZnO cluster with size of about 1.8 nm after absorption of one photon of 6.4 eV energy to be about 20 K. The num ber of photons absorbed by a particle irradiated at the uence of 30 mJ/cm^2 used in our experiments is estimated to be about 15 taking into account the nanocluster absorption e ciency [15]. This number gives a relatively good approximation of the cluster temperature of 550 600 K estimated from the PL spectra.

In order to con m the mechanism responsible for the red tail of the emission peak from ZnO nanoclusters we have excited the PL by a fem to second laser at the uence of about 300 J/cm² giving a slightly higher number of excited carriers than the nanosecond laser at a uence of 30 m J/cm². The concentration of free carriers (N) has been estimated using the rate equation:

$$\frac{dN}{dt} = G \quad \frac{N}{m}; \quad G = \frac{(1 \quad R) F}{laserh}; \quad (1)$$

where G is the carrier generation term, R is a re ectivity, is the absorption coe cient, F, laser and h are laser

uence, pulse duration and photon energy respectively. The lifetime of the excitons in bulk ZnO is measured to be of several tens to hundreds picoseconds depending on temperature [20]. Thus, two excitation regimes we used, nanosecond and fem to second, are principally different. In the case of the excitation with ns pulses the creation of hot carriers is a kinetic process mainly determined by recombination of the carriers in a material and by the excitation power (eq. 1). Finally, the nanocluster is heated by the accumulation of the excessive energy transfered from the new hot carriers created by absorption of photons.

C ontrarily to the quasistationary carrier concentration under ns excitation, the fs laser pulses being much shorter than the exciton life-time create the population of hot electron-hole pairs which is independent of their time of life. In this case the carrier concentration will be determ ined only by the carrier generation rate (G). These carriers are present in the material only during their lifetime. Thus, at nearly the same free carrier concentration a fs pulse induces signic cantly lower heating than the nanosecond one. It should be noted that the heat losses by collisional, radiative and evaporative cooling of the nanoclusters are negligible for both ns and fs excitation regimes [21]. Figure 5 presents typical photolum inescence spectra of free ZnO nanoclusters obtained after fem to second excitation. The clusters were prepared at the same laser

uence of 3.5 J/m^2 and at oxygen pressures of 6 and 8 m bar. The spectra have been taken two m inutes after the ablation run. The shape of the lum inescence band appears to be independent on the gas pressure and it is very close to that observed in ZnO nanocrystalline Im s (Fig. 5c). Both high and low energy tails observed in g. 5 are strongly reduced com pared to the PL under nanosecond excitation. This fact allows us to attribute the low-energy tail of the spectra taken under nanosecond excitation to heating of the nanoclusters during the laser pulse. We should note how ever that the reduced high energy tail of the excitonic spectra is probably caused by the bandgap renorm alization in the clusters with sizes below Bohr radius because the heating e ect is reduced under fs excitation. Absence of low -energy tail and the band maximum position at 3.28 eV also show that the m a prity of clusters reached the tem perature of the am bient gas after their synthesis.

- D. M. Bagnall, Y. F. Chen, Z. Zhu, T. Yao, S. Koyama, M.Y. Shen, and T. Goto, Appl. Phys. Lett. 70 (1997) 2230.
- [2] Z K. Tang, G K L. W ong, P. Yu, M. Kawasaki, A. O htom o, H K oinum a, Y. Segawa, Appl. Phys. Lett. 72 (1998) 3270.
- [3] S. Choopun, R D. Vispute, W. Noch, A. Balsamo, R P. Sharma, T. Venkatesan, A. Iliadis, D.C. Look, Appl. Phys.Lett. 75 (1998) 3947.
- [4] H. Cao, Y. G. Zhao, X. Liu, E.W. Seelig, R.P.H. Chang, Appl. Phys. Lett. 75 (2000) 1213.
- [5] K. Haga, M. Kamidaira, Y. Kashiwaba, T. Sekiguchi, H. Watanabe, J.Cryst. Growth 214 (215 (2000) 77.
- [6] K H. Yoon, JW . Choi, D H. Lee, Thin Solid Films 302 (1997) 116.
- [7] T. Nakamura, H. Minoura, H. Muto, Thin Silid Films 405 (2002) 109.
- [8] I. O zerov, D. Nelson, A.V. Bulgakov, W. Marine, M. Sentis, Appl. Surf. Sci. 212 (213 (2003) 349. (arX iv: cond-m at/0311315)
- [9] A B. Hartanto, X. Ning, Y. Nakata, T. Okada, Appl. Phys. A 78 (2004) 299.
- [10] E. Millon, O. Albert, J.C. Loulergue, J. Etchepare, D. Hulin, W. Seiler, J. Perriere, J. Appl. Phys. 88 (2002) 6937.

IV. CONCLUSIONS

We observed condensation and aggregation of ZnO nanoclusters prepared by pulsed laser ablation in gas phase. The nanoclusters suspended in the ambient oxygen gas are already crystallized and cooled down showing optical properties similar to those for solid Im s. Under nanosecond laser excitation the photolum inescence spectra of the interband recombination from the nanoclusters show the nanocluster heating by the accumulation of the energy transfered from the hot carriers. Under fem tosecond laser excitation, when the thermale ect of laser irraditation is strongly reduced, the nanoclusters with sizes of several nanom eters show a very ecient UV lum inescence com parable to that of the high quality Im s.

- [11] W .M arine, L.Patrone, B.Luk'yanchuk, M .Sentis, Appl. Surf. Sci. 154 (155 (2000) 345.
- [12] Y. Kawaguchi, A. Narazaki, T. Sato, H. Nino, A. Yabe, Appl. Surf. Sci. 197 (198 (2002) 268.
- [13] F. Claeyssens, A. Cheesman, S.J. Henley, M. N. R. Ashfold, J. Appl. Phys. 92 (2002) 6886.
- [14] A.V. Bulgakov, I. O zerov, W. Marine, E-print (2003) http://arXiv.org/abs/physics/0311117.
- [15] L.Boufendi, J.Hermann, A.Bouchoule, B.Dubreuil, E. Sto els, W W. Sto els, M L. de Giorgi, J.Appl.Phys. 76 (1994) 148.
- [16] I.O zerov, A.V. Bulgakov, D.Nelson, R.Castell, M.Sentis, and W. Marine, J.Phys. IV 108 (2003) 37. (arXiv: physics/0311053)
- [17] A. van Dijken, J. Makkinje, A. Meijerink, J. Lum. 92 (2001) 323.
- [18] L.W ang, N.C.Giles, J.Appl. Phys. 94 (2003) 973.
- [19] A. Yam am oto, T. Kido, T. Goto, Y. Chen, T. Yao, Solid State Commun. 122, 29 (2002).
- [20] V. V. Travnikov, A. Freiberg, S.F. Savikhin, J. Lum. 47 (1990) 107.
- [21] B S.Luk'yanchuk, W .M arine, Appl. Surf. Sci. 154 { 155 (2000) 314.